General Purpose Amplifier Transistor

NPN Surface Mount

Features

- Moisture Sensitivity Level: 1
- Pb–Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	60	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	50	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	7.0	Vdc
Collector Current – Continuous	Ι _C	100	mAdc
Collector Current – Peak	I _{C(P)}	200	mAdc

THERMAL CHARACTERISTICS

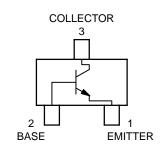
Characteristic	Symbol	Max	Unit
Power Dissipation	PD	200	mW
Junction Temperature	Τ _J	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

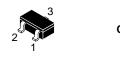
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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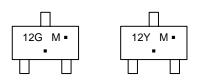
http://onsemi.com

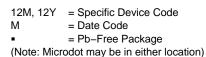




SC-59 CASE 318D STYLE 1

MARKING DIAGRAMS





ORDERING INFORMATION

Device	Package	Shipping [†]
MSC2712GT1	SC-59	3000/Tape & Reel
MSC2712GT1G	SC–59 (Pb–Free)	3000/Tape & Reel
MSC2712YT1	SC-59	3000/Tape & Reel
MSC2712YT1G	SC–59 (Pb–Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

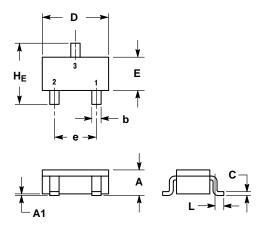
Characteristic		Symbol	Min	Мах	Unit
Collector–Emitter Breakdown Voltage $(I_C = 2.0 \text{ mAdc}, I_B = 0)$		V _{(BR)CEO}	50	_	Vdc
Collector–Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$		V _{(BR)CBO}	60	_	Vdc
Emitter–Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$		V _{(BR)EBO}	7.0	_	Vdc
Collector–Base Cutoff Current ($V_{CB} = 45 \text{ Vdc}, I_E = 0$)		I _{CBO}	-	0.1	μAdc
		I _{CEO}	- - -	0.1 2.0 1.0	μAdc μAdc mAdc
	2712GT1 22712YT1	h _{FE}	200 120	400 240	-
Collector–Emitter Saturation Voltage $(I_C = 100 \text{ mAdc}, I_B = 10 \text{ mAdc})$		V _{CE(sat)}	-	0.5	Vdc
Current-Gain – Bandwidth Product ($I_C = 1 \text{ mA}, V_{CE} = 10.0 \text{ V}, f = 10 \text{ MHz}$)		f _T	50	_	MHz

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

1. Pulse Test: Pulse Width \leq 300 $\mu s,\, D.C. \leq$ 2%.

PACKAGE DIMENSIONS

SC-59 CASE 318D-04 ISSUE G

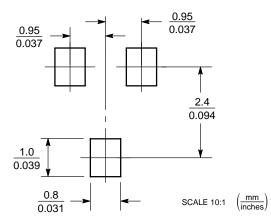


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.00	1.15	1.30	0.0394	0.0453	0.0511
A1	0.013	0.06	0.100	0.0005	0.0022	0.0040
b	0.35	0.43	0.50	0.0138	0.0167	0.0196
c	0.09	0.14	0.18	0.0034	0.0053	0.0070
D	2.70	2.90	3.10	0.1063	0.1142	0.1220
Е	1.30	1.50	1.70	0.0512	0.0591	0.0669
е	1.70	1.90	2.10	0.0670	0.0748	0.0826
L	0.20	0.40	0.60	0.0079	0.0157	0.0236
HE	2.50	2.80	3.00	0.1102	0.1102	0.1181

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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